Octal Counter

The MC14022B is a four-stage Johnson octal counter with built-in code converter. High-speed operation and spike-free outputs are obtained by use of a Johnson octal counter design. The eight decoded outputs are normally low, and go high only at their appropriate octal time period. The output changes occur on the positive-going edge of the clock pulse. This part can be used in frequency division applications as well as octal counter or octal decode display applications.

Features

- Fully Static Operation
- DC Clock Input Circuit Allows Slow Rise Times
- Carry Out Output for Cascading
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load Over the Rated Temperature Range
- Pin-for-Pin Replacement for CD4022B
- Triple Diode Protection on All Inputs
- Pb-Free Packages are Available*

MAXIMUM RATINGS (Voltages Referenced to VSS)

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage Range	-0.5 to +18.0	V
V _{in} , V _{out}	Input or Output Voltage Range (DC or Transient)	-0.5 to V _{DD} + 0.5	V
I _{in} , I _{out}	Input or Output Current (DC or Transient) per Pin	±10	mA
P _D	Power Dissipation, per Package (Note 1)	500	mW
T _A	Ambient Temperature Range	-55 to +125	°C
T _{stg}	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature (8–Second Soldering)	260	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Temperature Derating:

Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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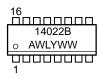
MARKING DIAGRAMS



PDIP-16 P SUFFIX CASE 648 16<u>ኩሉ ሉ ሉ ሉ ሉ ሉ ሉ</u> MC14022BCP o AWLYYWW 1 **ታ** ታ ታ ታ ታ ታ ታ ታ ታ



SOIC-16 D SUFFIX CASE 751B



A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week

ORDERING INFORMATION

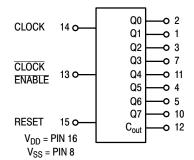
See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

PIN ASSIGNMENT

Q1 [1 ●	16	V _{DD}
Q0 [2	15] R
Q2 [3	14	С
Q5 [4	13	CE
Q6 [5	12	C _{out}
NC [6	11	Q4
Q3 [7	10] Q7
v _{ss} [8	9] ис

NC = NO CONNECTION

BLOCK DIAGRAM



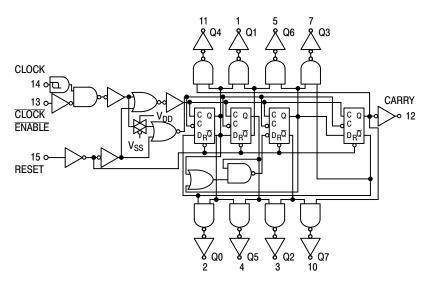
NC = PIN 6, 9

FUNCTIONAL TRUTH TABLE (Positive Logic)

	Clock	Clock Enable	Reset	Output=n
Ī	0	Х	0	n
	Χ	1	0	n
		0	0	n+1
	~	Χ	0	n
	1	~	0	n+1
	Χ	_	0	n
	Χ	Х	1	Q0

X = Don't Care. If n < 4 Carry = 1, Otherwise = 0.

LOGIC DIAGRAM



ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

				- 5	5°C		25°C		125	°C	
Characteristic		Symbol	V _{DD} Vdc	Min	Max	Min	Typ (Note 2)	Max	Min	Max	Unit
Output Voltage V _{in} = V _{DD} or 0	"0" Level	V _{OL}	5.0 10 15	_ _ _	0.05 0.05 0.05	_ _ _	0 0 0	0.05 0.05 0.05	_ _ _	0.05 0.05 0.05	Vdc
V _{in} = 0 or V _{DD}	"1" Level	V _{OH}	5.0 10 15	4.95 9.95 14.95	_ _ _	4.95 9.95 14.95	5.0 10 15	_ _ _	4.95 9.95 14.95	_ _ _	Vdc
Input Voltage $(V_O = 4.5 \text{ or } 0.5 \text{ Vdc})$ $(V_O = 9.0 \text{ or } 1.0 \text{ Vdc})$ $(V_O = 13.5 \text{ or } 1.5 \text{ Vdc})$	"0" Level	V _{IL}	5.0 10 15	_ _ _	1.5 3.0 4.0	_ _ _	2.25 4.50 6.75	1.5 3.0 4.0	_ _ _	1.5 3.0 4.0	Vdc
$(V_O = 0.5 \text{ or } 4.5 \text{ Vdc})$ $(V_O = 1.0 \text{ or } 9.0 \text{ Vdc})$ $(V_O = 1.5 \text{ or } 13.5 \text{ Vdc})$	"1" Level	V _{IH}	5.0 10 15	3.5 7.0 11	_ _ _	3.5 7.0 11	2.75 5.50 8.25	_	3.5 7.0 11		Vdc
Output Drive Current $ (V_{OH} = 2.5 \text{ Vdc}) $ $ (V_{OH} = 4.6 \text{ Vdc}) $ $ (V_{OH} = 9.5 \text{ Vdc}) $ $ (V_{OH} = 13.5 \text{ Vdc}) $	Source	ГОН	5.0 5.0 10 15	- 3.0 - 0.64 - 1.6 - 4.2	_ _ _ _	- 2.4 - 0.51 - 1.3 - 3.4	- 4.2 - 0.88 - 2.25 - 8.8	_ _ _ _	- 1.7 - 0.36 - 0.9 - 2.4	_ _ _	mAdc
$(V_{OL} = 0.4 \text{ Vdc})$ $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$	Sink	I _{OL}	5.0 10 15	0.64 1.6 4.2	_ _ _	0.51 1.3 3.4	0.88 2.25 8.8	_ _ _	0.36 0.9 2.4	_ _ _	mAdc
Input Current		I _{in}	15	_	± 0.1	_	±0.00001	± 0.1	_	± 1.0	μAdc
Input Capacitance (V _{in} = 0)		C _{in}	_	_	_	_	5.0	7.5	_	_	pF
Quiescent Current (Per Package)		I _{DD}	5.0 10 15	_ _ _	5.0 10 20	_ _ _	0.005 0.010 0.015	5.0 10 20	_ _ _	150 300 600	μAdc
Total Supply Current (Note (Dynamic plus Quiesce Per Package) (C _L = 50 pF on all outpout buffers switching)	ent,	I _T	5.0 10 15			$I_{T} = (0)$.28 μΑ/kHz)f .56 μΑ/kHz)f .85 μΑ/kHz)f	+ I _{DD}			μAdc

Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
 The formulas given are for the typical characteristics only at 25°C.
 To calculate total supply current at loads other than 50 pF:

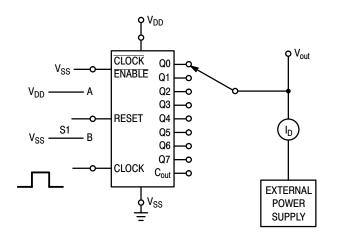
$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

where: I_T is in μA (per package), C_L in pF, V = ($V_{DD} - V_{SS}$) in volts, f in kHz is input frequency, and k = 0.00125.

SWITCHING CHARACTERISTICS (Note 5) ($C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}$)

Characteristic	Symbol	V _{DD} Vdc	Min	Typ (Note 6)	Max	Unit
Output Rise and Fall Time $t_{TLH}, t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ $t_{TLH}, t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ $t_{TLH}, t_{THL} = (0.55 \text{ ns/pF}) C_L + 9.5 \text{ ns}$	t _{TLH} , t _{THL}	5.0 10 15		100 50 40	200 100 80	ns
Propagation Delay Time Reset to Decode Output tpLH, tpHL = (1.7 ns/pF) C _L + 415 ns tpLH, tpHL = (0.66 ns/pF) C _L + 197 ns tpLH, tpHL = (0.5 ns/pF) C _L + 150 ns	t _{PLH} , t _{PHL}	5.0 10 15	_ _ _	500 230 175	1000 460 350	ns
Propagation Delay Time Clock to C_{out} t_{PLH} , t_{PHL} = (1.7 ns/pF) C_L + 315 ns t_{PLH} , t_{PHL} = (0.66 ns/pF) C_L + 142 ns t_{PLH} , t_{PHL} = (0.5 ns/pF) C_L + 100 ns	t _{PLH} , t _{PHL}	5.0 10 15	_ _ _	400 175 125	800 350 250	ns
Propagation Delay Time Clock to Decode Output tpLH, tpHL = (1.7 ns/pF) C _L + 415 ns tpLH, tpHL = (0.66 ns/pF) C _L + 197 ns tpLH, tpHL = (0.5 ns/pF) C _L + 150 ns	t _{PLH} , t _{PHL}	5.0 10 15	_ _ _	275 125 95	1000 460 350	ns
Turn–Off Delay Time Reset to C_{out} $t_{PLH} = (1.7 \text{ ns/pF}) C_L + 315 \text{ ns}$ $t_{PLH} = (0.66 \text{ ns/pF}) C_L + 142 \text{ ns}$ $t_{PLH} = (0.5 \text{ ns/pF}) C_L + 100 \text{ ns}$	t _{PLH}	5.0 10 15	_ _ _	400 175 125	800 350 250	ns
Clock Pulse Width	t₩H	5.0 10 15	250 100 75	125 50 35	_ _ _	ns
Clock Frequency	f _{cl}	5.0 10 15	_ _ _	5.0 12 16	2.0 5.0 6.7	MHz
Reset Pulse Width	t₩H	5.0 10 15	500 250 190	250 125 95	_ _ _	ns
Reset Removal Time	t _{rem}	5.0 10 15	750 275 210	375 135 105	_ _ _	ns
Clock Input Rise and Fall Time	t _{TLH} , t _{THL}	5.0 10 15		No Limit		_
Clock Enable Setup Time	t _{su}	5.0 10 15	350 150 115	175 75 52	_ _ _	ns
Clock Enable Removal Time	t _{rem}	5.0 10 15	420 200 140	260 100 70	_ _ _	ns

^{5.} The formulas given are for the typical characteristics only at 25°C.
6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.



	Output Sink Drive	Output Source Drive
Outputs	(S1 to A)	Clock to desired Output (S1 to B)
Carry	Clock to Q5 thru Q7 (S1 to B)	S1 to A
V _{GS} =	V_{DD}	– V _{DD}
V _{DS} =	V _{out}	V _{out} – V _{DD}

Figure 1. Typical Output Source and Output Sink Characteristics Test Circuit

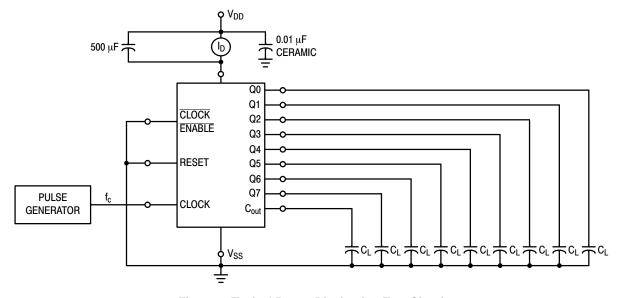


Figure 2. Typical Power Dissipation Test Circuit

APPLICATIONS INFORMATION

Figure 3 shows a technique for extending the number of decoded output states for the MC14022B. Decoded outputs are sequential within each stage and from stage to stage, with no dead time (except propagation delay).

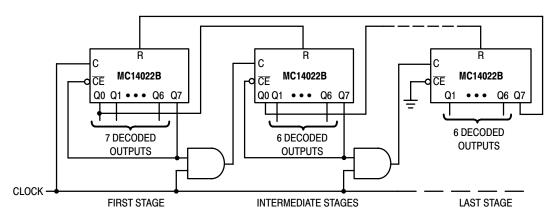


Figure 3. Counter Expansion

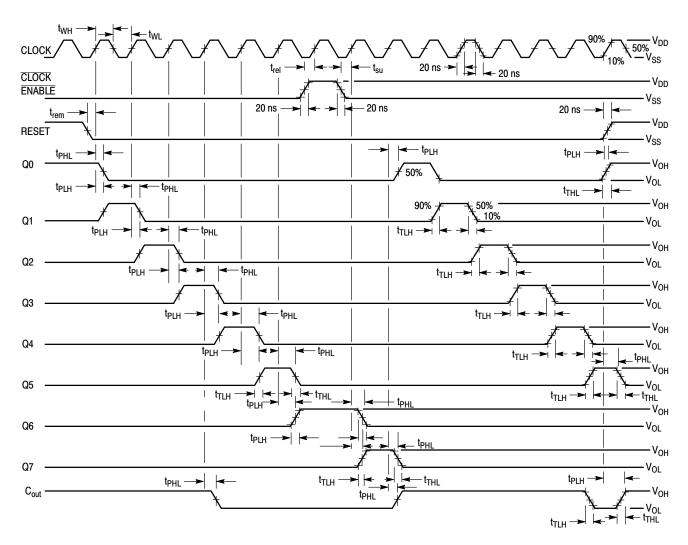


Figure 4. AC Measurement Definition and Functional Waveforms

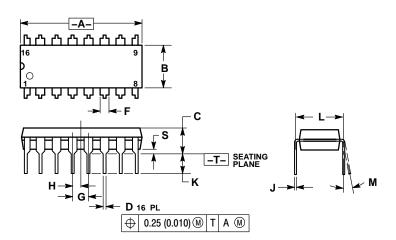
ORDERING INFORMATION

Device	Package	Shipping [†]
MC14022BCP	PDIP-16	500 Units / Rail
MC14022BCPG	PDIP-16 (Pb-Free)	500 Units / Rail
MC14022BD	SOIC-16	48 Units / Rail
MC14022BDG	SOIC-16 (Pb-Free)	48 Units / Rail
MC14022BDR2	SOIC-16	2500 Units / Tape & Reel
MC14022BDR2G	SOIC-16 (Pb-Free)	2500 Units / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

PDIP-16 **P SUFFIX** PLASTIC DIP PACKAGE CASE 648-08 ISSUE T

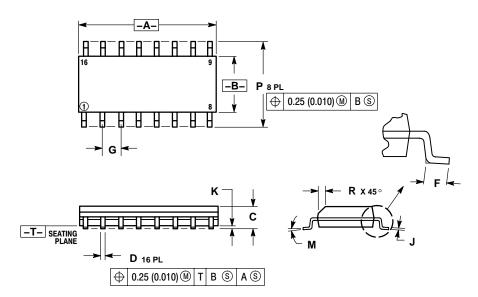


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS
DIM	MIN MAX		MIN	MAX
Α	0.740	0.770	18.80	19.55
В	0.250	0.270	6.35	6.85
С	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100	BSC	2.54 BSC	
Н	0.050	BSC	1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0°	10 °	0°	10 °
S	0.020	0.040	0.51	1.01

PACKAGE DIMENSIONS

SOIC-16 D SUFFIX PLASTIC SOIC PACKAGE CASE 751B-05 ISSUE J



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 Y14.5M. 1982.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE
 MOLD PROTEUCION
- MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006)
 PER SIDE.
- 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MIN MAX		MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050	BSC
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
Р	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

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